Diode Semiconductor Device - Page 1 of 1



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Inc	losure Material:
Gla	ISS
Ter	minal Length:
1.0	00 inches
Ele	ctrode Internally-electrically Connected To Case:
Cat	thode
Мо	unting Method:
Ter	minal
Ter	minal Circle Diameter:
0.0	40 inches
Vol	tage Rating In Volts Per Characteristic:
5.6	regulator voltage
Vol	tage Tolerance In Percent:
-5.0	0/+5.0
Ma	ximum Operating Tempurature Per Measurement Point:
175	5.0 degrees celsius ambient air
Ter	minal Type And Quantity:
2 u	ninsulated wire lead
She	elf Life:
N/a	l de la constante de
Uni	it Of Measure:
Dei	militarization:
No	
Fiig	g:
	10a0